Si photodiodes with preamp

S9295 series

Large area photodiode integrated with op amp and TE-cooler

The S9295 series is a thermoelectrically cooled Si photodiode with preamp developed for low-light-level detection. A large area photodiode, op amp, TE-cooler and feedback resistor (10 GΩ) are integrated into a single package. A thermistor is also included in the same package for temperature control so that the photodiode and I-V conversion circuit can be cooled for stable operation. The S9295 series also features low noise and low NEP, and is especially suitable for NOx detection. The photosensitive area of the photodiode is internally connected to the GND terminal making it highly resistant to EMC noise.

Features

- Large photosensitive area: 10 × 10 mm
- UV to NIR Si photodiode optimized for precision photometry
- Compact hermetic package with sapphire window
- High precision FET input operational amplifier
- High gain: Rf=10 GΩ
- Low noise and NEP
- High cooling efficiency
  - S9295: ΔT=50 °C
  - S9295-01: ΔT=30 °C
- High stability with thermistor
- Highly resistant to EMC noise

Applications

- NOx detection
- Low-light-level measurement, etc.

Absolute maximum ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply voltage (preamp)</td>
<td>Vcc</td>
<td>±20 V</td>
</tr>
<tr>
<td>Operating temperature</td>
<td>Topr</td>
<td>-30 to +60 °C</td>
</tr>
<tr>
<td>Storage temperature</td>
<td>Tstg</td>
<td>-40 to +80 °C</td>
</tr>
<tr>
<td>TE-cooler allowable voltage*1</td>
<td>Vte</td>
<td>5 V²</td>
</tr>
<tr>
<td>TE-cooler allowable current*2</td>
<td>Ite</td>
<td>1 A</td>
</tr>
<tr>
<td>Thermistor power dissipation</td>
<td>Pth</td>
<td>0.2 mW</td>
</tr>
</tbody>
</table>

*1: Ripple max.: 10%
*2: S9295-01: 3.7 V

Recommended operating conditions

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply voltage (preamp)</td>
<td>Vcc</td>
<td>±5 to ±15 V</td>
</tr>
<tr>
<td>TE-cooler current</td>
<td>Ite</td>
<td>0.8 A max.</td>
</tr>
<tr>
<td>Thermistor power dissipation</td>
<td>Pth</td>
<td>0.03 mW max.</td>
</tr>
<tr>
<td>Load resistance</td>
<td>RL</td>
<td>100 kΩ min.</td>
</tr>
</tbody>
</table>

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.
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Electrical and optical characteristics (Typ. Vcc=±15 V, RL=1 MΩ)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Condition</th>
<th>S9295</th>
<th>S9295-01</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Spectral response range</td>
<td>λ</td>
<td></td>
<td></td>
<td></td>
<td>nm</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Td=-25 °C</td>
<td>190 to 1100</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Peak sensitivity wavelength</td>
<td>λp</td>
<td></td>
<td>960</td>
<td></td>
<td>nm</td>
</tr>
<tr>
<td>Feedback resistance (built-in)*3</td>
<td>Rf</td>
<td></td>
<td>10</td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td>Photosensitivity</td>
<td>S</td>
<td>λ=200 nm</td>
<td>0.9</td>
<td></td>
<td>V/nW</td>
</tr>
<tr>
<td></td>
<td></td>
<td>λ=λp</td>
<td>5.1</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Output noise voltage</td>
<td>Vn</td>
<td>Dark state, f=10 Hz</td>
<td>20</td>
<td>25</td>
<td>μV rms/Hz1/2</td>
</tr>
<tr>
<td>Noise equivalent power</td>
<td>NEP</td>
<td>λ=λp, f=10 Hz</td>
<td>4</td>
<td>5</td>
<td>fW/Hz1/2</td>
</tr>
<tr>
<td>Output offset voltage</td>
<td>Vos</td>
<td>Dark state</td>
<td>±2</td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>Cutoff frequency</td>
<td>fc</td>
<td>-3 dB</td>
<td>190</td>
<td>180</td>
<td>Hz</td>
</tr>
<tr>
<td>Output voltage swing</td>
<td>Vo</td>
<td></td>
<td>13</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Supply current</td>
<td>Icc</td>
<td>Dark state</td>
<td>0.3</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>Thermistor resistance</td>
<td>Rth</td>
<td></td>
<td>86</td>
<td>30</td>
<td>kΩ</td>
</tr>
</tbody>
</table>

*3: Custom devices are available with different Rf values and/or internal Cf, etc.

Spectral response

![Spectral response graph](Typ. Vcc=±15 V)

Frequency response

![Frequency response graph](Typ. Vcc=±15 V)
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**NEP vs. frequency**

![NEP vs. frequency graph](image)

- **S9295**
- **S9295-01**

**Output noise voltage vs. frequency**

![Output noise voltage vs. frequency graph](image)

- **S9295**
- **S9295-01**

**Element temperature vs. TE-cooler current**

<table>
<thead>
<tr>
<th><strong>S9295</strong></th>
<th><strong>S9295-01</strong></th>
</tr>
</thead>
<tbody>
<tr>
<td><img src="image" alt="Element temperature vs. TE-cooler current graph" /></td>
<td><img src="image" alt="Element temperature vs. TE-cooler current graph" /></td>
</tr>
</tbody>
</table>

- **Vte vs. Ite**
- **Td vs. Ite**
- **Td vs. Ite**

**Output noise voltage vs. frequency**

- **Typ. Vcc=±15 V**

**Element temperature vs. TE-cooler current**

- **Typ. Ta=25 °C**

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S9295 series

External connection

Thermistor resistance vs. temperature

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A tantalum or ceramic capacitor of 0.1 to 10 μF must be connected to the supply voltage leads (pins ④ and ⑦) as a bypass capacitor used to prevent the device from oscillation.
Precautions

ESD
The S9295 series may be damaged or their performance may deteriorate by such factors as electro static discharge from the human body, surge voltage from measurement equipment, leakage voltages from soldering irons and packing materials. As a countermeasure against electro static discharge, the device, operator, work place and measuring jigs must all be set at the same potential. The following precautions must be observed during use:

- To protect the device from electro static discharge which accumulate on the operator or the operator,s clothes, use a wrist strap or similar tools to ground the operator,s body via a high impedance resistor (1 MΩ).
- A semiconductive sheet (1 MΩ to 10 MΩ) should be laid on both the work table and the floor in the work area.
- When soldering, use an electrically grounded soldering iron with an isolation resistance of more than 10 MΩ.
- For containers and packing, use of a conductive material or aluminum foil is effective. When using an antistatic material, use one with a resistance of 0.1 MΩ/cm² to 1 GΩ/cm².

Strength
- Thermoelectrically-cooler devices may be damaged if subjected to shock, for example drop impact. Take sufficient care when handling these devices.

Lead forming
- When forming the leads, take care not to apply excessive force to the lead sealing glass. Excessive force may impair the hermetic sealing, possibly degrading the cooling capacity. To form the leads, hold the roots of the leads securely with a pair of pliers and bend them.

Heatsink
- Use a heatsink with thermal resistance less than 1.3 °C/W. Apply thermal grease between the heatsink and detector package, and then fasten them with the screws. Be careful not to give any excessive force or mechanical stress to the detector package at this point.

Wiring
- Be careful not to misconnect the plus and minus leads of the thermoelectric cooler or preamplifier. Supplying a voltage or current while these connections are reversed may damage the device.
- The feedback resistor integrated into S9295 series is high so it is susceptible to external noise. Always ground the case terminal when using S9295.

Against UV light exposure
- When UV light irradiation is applied, the product characteristics may degrade. Such examples include degradation of the product’s UV sensitivity and increase in dark current. This phenomenon varies depending on the irradiation level, irradiation intensity, usage time, and ambient environment and also varies depending on the product model. Before employing the product, we recommend that you check the tolerance under the ultraviolet light environment that the product will be used in.
- Exposure to UV light may cause the characteristics to degrade due to gas released from the resin bonding the product’s component materials. As such, we recommend that you avoid applying UV light directly on the resin and apply it on only the inside of the photosensitive area by using an aperture or the like.
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Related information
www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- Metal, ceramic, plastic package products
- Technical information
- Si photodiode/Application circuit examples

Information described in this material is current as of October, 2015.
Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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